









	<h2 style="color: #E67E22;">SI3586DV-T1-GE3</h2>
 <p>Image may be representation. See specs for product details.</p>	Hersteller-Teilenummer: SI3586DV-T1-GE3
	Hersteller / Marke: Electro-Films (EFI) / Vishay
	Teil der Beschreibung: MOSFET N/P-CH 20V 2.9A 6-TSOP
	Datenblätter:  SI3586DV-T1-GE3.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 125897 pcs Stock Available.
Liefern von: Hong Kong	
Versandweg: DHL/Fedex/TNT/UPS/EMS	

Spezifikationen

Teilenummer	SI3586DV-T1-GE3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET N/P-CH 20V 2.9A 6-TSOP
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	125897 pcs Stock
detaillierte Beschreibung	Mosfet Array N and P-Channel 20V 2.9A, 2.1A 830mW
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	830mW
Verpackung / Gehäuse	SOT-23-6 Thin, TSOT-23-6
Supplier Device-Gehäuse	6-TSOP
Typ FET	N and P-Channel
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	2.9A, 2.1A
Rds On (Max) @ Id, Vgs	60 mOhm @ 3.4A, 4.5V
VGS (th) (Max) @ Id	1.1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	6nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)
Basisteilenummer	SI3586
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SI3586DV-T1-GE3TR


















































SI3586DV-T1-GE3 ist neu im Original, Suche SI3586DV-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI3586DV-T1-GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI3586DV-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI3588DV-T1-E3 Electro-Films (EFI) / Vishay MOSFET N/P-CH 20V 2.5A 6TSOP</p>	 <p>SI3586DV-T1-E3 Vishay / Siliconix MOSFET N/P-CH 20V 2.9A 6TSOP</p>	 <p>SI3588DV-T1-GE3 Vishay / Siliconix MOSFET N/P-CH 20V 2.5A 6- TSOP</p>	 <p>SI3586DS-TI-E3 Vishay Precision Group SI3586DS-TI-E3 VISHAY</p>
 <p>SI3588DV-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N/P-CH 20V 2.5A 6- TSOP</p>	 <p>SI3586DV-T1-E3 Electro-Films (EFI) / Vishay MOSFET N/P-CH 20V 2.9A 6TSOP</p>	 <p>SI3586DV VISHAY SI3586DV VISHAY</p>	 <p>SI3588DV-T1-E3 Vishay / Siliconix MOSFET N/P-CH 20V 2.5A 6TSOP</p>

heiße Teile

Mehr

 SI3499DV-T1-E3	 SI3499DV-T1-GE3	 SI3499DV-T1-GE3	 SI3500-A-GM	 SI3529DV-T1-GE3
 SI3529DV-T1-GE3	 SI3552DV	 SI3552DV-T1	 SI3552DV-T1-E3	 SI3552DV-T1-E3
 SI3552DV-T1-GE3	 SI3552DV-T1-GE3	 SI3585CDV	 SI3585CDV-T1-GE3	 SI3585CDV-T1-GE3
 SI3585DV	 SI3585DV-T1	 SI3585DV-T1-E3	 SI3585DV-T1-E3	 SI3585DV-T1-GE3
 SI3585DV-T1-GE3	 SI3586DS-TI-E3	 SI3586DV	 SI3586DV-T1-E3	 SI3586DV-T1-E3
 SI3586DV-T1-GE3	 SI3588DV	 SI3588DV-T1-E3	 SI3588DV-T1-E3	 SI3588DV-T1-GE3
 SI3588DV-T1-GE3	 SI3590DV-T1-GE3	 SI3590DV-T1-GE3	 SI3801DV-T1	 SI3803DV-T1
 SI3805DV-T1	 SI3805DV-T1-E3	 SI3805DV-T1-E3	 SI3812DV-T1-GE3	 SI3812DV-T1-GE3
 SI3850ADV-T1-E3	 SI3850ADV-T1-E3	 SI3850ADV-T1-GE3	 SI3850ADV-T1-GE3	 SI3850DV-T1
 SI3850DV-T1-E3	 SI3850DV-T1-GE3	 SI3851DV	 SI3851DV-T1	 SI3851DV-T1-E3

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